

- 19.2 VOLT NOMINAL ZENER VOLTAGE $\pm 5\%$
- TEMPERATURE COMPENSATED ZENER REFERENCE DIODES
- LOW NOISE
- METALLURGICALLY BONDED
- DOUBLE PLUG CONSTRUCTION

1N4916
thru
1N4932A

MAXIMUM RATINGS

Operating Temperature: -65°C to $+175^{\circ}\text{C}$

Storage Temperature: -65°C to $+175^{\circ}\text{C}$

DC Power Dissipation: 500mW @ $+50^{\circ}\text{C}$

Power Derating: 4 mW / $^{\circ}\text{C}$ above $+50^{\circ}\text{C}$

REVERSE LEAKAGE CURRENT

$I_R = 15 \mu\text{A}$ @ 25°C & $V_R = 12\text{Vdc}$

ELECTRICAL CHARACTERISTICS @ 25°C , unless otherwise specified.

JEDEC TYPE NUMBER	TEST CURRENT I_{ZT} (Note 3)	VOLTAGE TEMPERATURE STABILITY ΔV_{ZT} (Note 2)	TEMPERATURE RANGE	EFFECTIVE TEMPERATURE COEFFICIENT	MAXIMUM DYNAMIC IMPEDANCE Z_{ZT} (Note 1)	MAXIMUM NOISE DENSITY N_D
	mA	mV	$^{\circ}\text{C}$	$\%/^{\circ}\text{C}$	OHMS	$\mu\text{V}/\sqrt{\text{Hz}}$
1N4916	0.5	144	+25 to +100	0.01	600	1.0
1N4916A	0.5	298	-55 to +100	0.01	600	1.0
1N4917	0.5	72	+25 to +100	0.005	600	1.0
1N4917A	0.5	149	-55 to +100	0.005	600	1.0
1N4918	0.5	29	+25 to +100	0.002	600	1.0
1N4918A	0.5	60	-55 to +100	0.002	600	1.0
1N4919	1.0	144	+25 to +100	0.01	300	0.5
1N4919A	1.0	298	-55 to +100	0.01	300	0.5
1N4920	1.0	72	+25 to +100	0.005	300	0.5
1N4920A	1.0	149	-55 to +100	0.005	300	0.5
1N4921	1.0	29	+25 to +100	0.002	300	0.5
1N4921A	1.0	60	-55 to +100	0.002	300	0.5
1N4922	2.0	144	+25 to +100	0.01	150	0.25
1N4922A	2.0	298	-55 to +100	0.01	150	0.25
1N4923	2.0	72	+25 to +100	0.005	150	0.25
1N4923A	2.0	149	-55 to +100	0.005	150	0.25
1N4924	2.0	29	+25 to +100	0.002	150	0.25
1N4924A	2.0	60	-55 to +100	0.002	150	0.25
1N4925	4.0	144	+25 to +100	0.01	75	0.22
1N4925A	4.0	298	-55 to +100	0.01	75	0.22
1N4926	4.0	72	+25 to +100	0.005	75	0.22
1N4926A	4.0	149	-55 to +100	0.005	75	0.22
1N4927	4.0	29	+25 to +100	0.002	75	0.22
1N4927A	4.0	60	-55 to +100	0.002	75	0.22
1N4928	4.0	14	+25 to +100	0.001	75	0.22
1N4928A	4.0	30	-55 to +100	0.001	75	0.22
1N4929	7.5	144	+25 to +100	0.01	36	0.20
1N4929A	7.5	298	-55 to +100	0.01	36	0.20
1N4930	7.5	72	+25 to +100	0.005	36	0.20
1N4930A	7.5	149	-55 to +100	0.005	36	0.20
1N4931	7.5	29	+25 to +100	0.002	36	0.20
1N4931A	7.5	60	-55 to +100	0.002	36	0.20
1N4932	7.5	14	+25 to +100	0.001	36	0.20
1N4932A	7.5	30	-55 to +100	0.001	36	0.20

NOTE 1 Zener impedance is derived by superimposing on I_{ZT} A 60Hz rms a.c. current equal to 10% of I_{ZT} .

NOTE 2 The maximum allowable change observed over the entire temperature range i.e., the diode voltage will not exceed the specified mV at any discrete temperature between the established limits, per JEDEC standard No.5.

NOTE 3 Zener voltage range equals 19.2 volts $\pm 5\%$.



FIGURE 1

DESIGN DATA

CASE: Hermetically sealed glass case. DO – 35 outline.

LEAD MATERIAL: Copper clad steel.

LEAD FINISH: Tin / Lead

POLARITY: Diode to be operated with the banded (cathode) end positive.

MOUNTING POSITION: Any.



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1N4916 thru 1N4932A



FIGURE 2

ZENER IMPEDANCE VS. OPERATING CURRENT



FIGURE 3

TYPICAL CHANGE OF TEMPERATURE COEFFICIENT
WITH CHANGE IN OPERATING CURRENT